## NSN 5961-00-558-7933

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Internal Configuration:
Junction contact
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 40.0 breakdown voltage, collector-to-emitter, base
open and 5.0 breakdown voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
50.00 microamperes zero-gate-voltage source current preset
Transfer Ratio:
20.0 static forward current transfer ratio, common-emitter
Special Features:
Junction pattern arrangement: npn
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0